NSN 5962-01-262-9879

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View Online at https://aerobasegroup.com/nsn/5962-01-262-9879 **Body Length:** 0.358 inches **Body Width:** 0.358 inches **Body Height:** 0.100 inches **Maximum Power Dissipation Rating:** 2.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and monolithic and bipolar and programmed **Inclosure Material:** Ceramic **Inclosure Configuration:** Leadless flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 14 input **Case Outline Source And Designator:** C-2 mil-m-38510 **Terminal Surface Treatment:** Solder **Product Name:** 14-input 4-output and/or invert gate array **Voltage Rating And Type Per Characteristic:** 12.0 volts power source **Time Rating Per Chacteristic:** 45.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Pal **Test Data Document:** 96906-mil-std-883b standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 20 leadless Shelf Life: N/a

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Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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